MAX44285

Dual-Channel, High-Precision, High-Voltage, Current-Sense Amplifier

General Description

The MAX44285 dual-channel high-side current-sense amplifier has precision accuracy specifications of V_{OS} less than 12 μ V (max) and gain error less than 0.1% (max).

The MAX44285 features an input common-mode voltage range from 2.7V to 76V with 80kHz of small-signal bandwidth, which makes it ideal for interfacing with a SAR ADC for multichannel multiplexed data acquisition systems.

The MAX44285 operates over the -40°C to +125°C temperature range. The MAX44285 is offered in 8-bump wafer-level package (WLP) and 8-pin μ MAX[®] package.

Applications

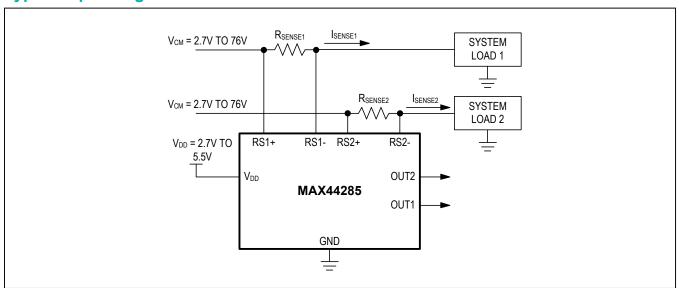
- Base Stations and Communication Equipment
- Power Management Systems
- Server Backplanes
- Industrial Control and Automation

Benefits and Features

- 2.7V to 76V Input Common Mode
- Low 12μV (max) Input Offset Voltage
- Low 0.1% (max) Gain Error
- Gain Options
 - G = 12.5V/V (MAX44285L)
 - G = 20V/V (MAX44285T)
 - G = 50V/V (MAX44285F)
 - G = 100V/V (MAX44285H)
- 1mm x 2mm 8-Bump WLP and 8-Pin μMAX Packages

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Typical Operating Circuit



Ordering Information appears at end of data sheet.



Dual-Channel, High-Precision, High-Voltage, Current-Sense Amplifier

Absolute Maximum Ratings

V _{DD} to GND0.3V to +6.0V RS+, RS- to GND0.3V to +80V RS+ to RS-	Continuous Power Dissipation (T _A = +70°C) WLP (derate 13.3mW/°C above +70°C)1064mW µMAX (derate 4.8mW/°C above +70°C)387.8mW
μMAX (1s maximum duration due to package thermal dissipation±80V	Operating Temperature Range
WLP (1s maximum duration due to package thermal dissipation±50V Continuous Input Current (Any Pin)±20mA	Storage Temperature Range65°C to +150°C Lead Temperature (soldering, 10s)(µMAX only)+300°C Soldering Temperature (reflow)+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Thermal Characteristics (Note 1)

WLP	μMAX
Junction-to-Ambient Thermal Resistance (θ _{JA})75°C/W	Junction-to-Ambient Thermal Resistance (θ _{JA})206.3°C/W
	Junction-to-Case Thermal Resistance (θ _{JC})42°C/W

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

Electrical Characteristics

 $(V_{RS+} = V_{RS-} = +76V, V_{DD} = +3.3V, V_{SENSE} = V_{RS+} - V_{RS-} = 1mV, T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DC CHARACTERISTICS						
Supply Voltage	V _{DD}	Guaranteed by PSRR	2.7		5.5	V
Supply Current		T _A = +25°C			1300	
Supply Current	I _{DD}	-40°C < T _A < +125°C		1500	μΑ	
Power-Supply Rejection Ratio	PSRR	2.7V ≤ V _{DD} ≤ 5.5V	110	120		dB
Input Common-Mode Voltage Range	V _{CM}	Guaranteed by CMRR	2.7		76	V
Input Bias Current at V _{RS+} and V _{RS-} (Note 3)	I _{RS+} , I _{RS-}				65	μА
Input Offset Current (Note 3)	I _{RS+} - I _{RS-}				1100	nA
Input Leakage Current (Note 3)	I _{RS+} , I _{RS-}	V _{DD} = 0V, V _{RS+} = 76V			6	μА
Common-Mode Rejection Ratio	CMRR	4.5V < V _{RS+} < 76V	125	140		dB
Input Offset Voltage	V	T _A = +25°C			±12	\/
(Note 3) Vos		-40°C ≤ T _A ≤ +125°C			±25	μV
Input Offset Voltage Drift (Note 3)	TCV _{OS}				130	nV/°C

Electrical Characteristics (continued)

 $(V_{RS+} = V_{RS-} = +76V, V_{DD} = +3.3V, V_{SENSE} = V_{RS+} - V_{RS-} = 1mV, T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 2)

PARAMETER	SYMBOL	COND	ITIONS	MIN	TYP	MAX	UNITS
		MAX44285L (G = 12.5V/V)			200		
Land Organ Nolland	.,	MAX44285T (G = 20V/V)			125		1
Input Sense Voltage	V_{SENSE}	MAX44285F (G = 50)	V/V)	50		- mV	
		MAX44285H (G = 100V/V)			25		
		Full-scale V _{SENSE} =	Full-scale V _{SENSE} = 200mV		12.5		
0 : 41 : 1)	0	Full-scale V _{SENSE} =	Full-scale V _{SENSE} = 125mV		20		.,,,,
Gain (Note 4)	G	Full-scale V _{SENSE} =	50mV	50		V/V	
		Full-scale V _{SENSE} =			100		
		T _A = +25°C				0.1	
Gain Error (Note 3)	GE	-40°C ≤ T _A ≤ +85°C			,	0.3	%
		-40°C ≤ T _A ≤ +125°C				0.5	
Output Resistance	R _{OUT}				0.1		mΩ
		Sink 500μA				15	
Output Low Voltage	V_{OL}	No load		4			mV
Output High Voltage	V _{OH}	Source 500µA		V _{DD} - 0.015			V
AC CHARACTERISTICS				I			I
Signal Bandwidth	BW -3dB	All gain configuration	All gain configurations V _{SENSE} > 5mV		80		kHz
AC Power-Supply Rejection Ratio	AC PSRR	f = 200kHz			40		dB
		1mV sine wave			54		
AC CMRR	AC CMRR	f = 200kHz	20mV sine wave		47		dB
Output Transient Recovery Time		$\Delta V_{OUT} = 2V_{P-P}$, 14-b and 1nF, 6nF ADC sa			2		μs
	_	With 250Ω isolation r	esistor		20		nF
Capacitive Load Stability	C_{LOAD}	Without any isolation resistor			200		pF
Input Voltage-Noise Density	e _n	f = 1kHz			45		nV/√Hz
Total Harmonic Distortion (Up to 7th Harmonics)	THD	f = 1kHz, V _{OUT} = 1V _{P-P}			63		dB
Power-Up Time (Note 5)					200		μs
Saturation Recovery Time					10		μs

Note 2: All devices are 100% production tested at $T_A = +25^{\circ}C$. All temperature limits are guaranteed by design.

Note 3: Specifications are guaranteed by design, not production tested.

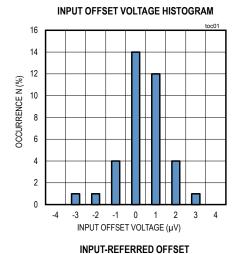
Note 4: Gain and offset voltage are calculated based on two point measurements: V_{SENSE1} and V_{SENSE2}.

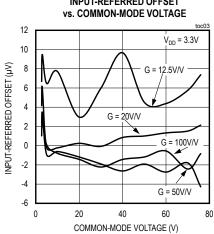
V_{SENSE1} = 20% x Full Scale V_{SENSE}. V_{SENSE2} = 80% x Full Scale V_{SENSE}.

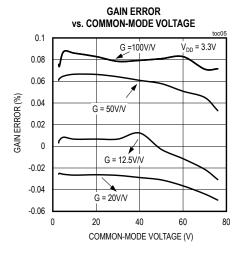
Note 5: Output is high-Z during power-up.

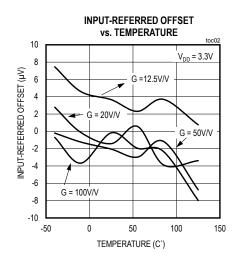
Typical Operating Characteristics

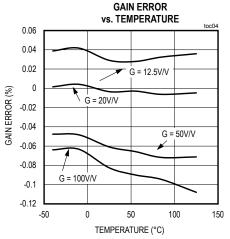
 $(V_{RS+} = V_{RS-} = 76V, V_{DD} = 3.3V, V_{SENSE} = V_{RS+} - V_{RS-} = 1mV, T_A = +25^{\circ}C$, unless otherwise noted.) (Note 2)

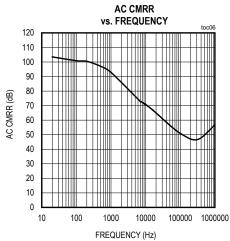






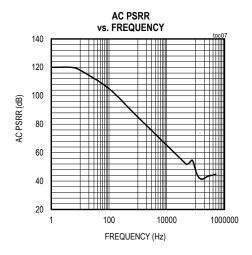


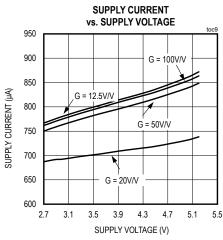


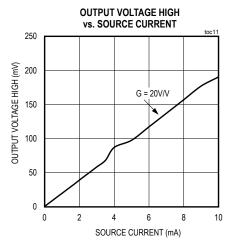


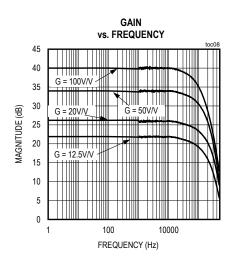
Typical Operating Characteristics (continued)

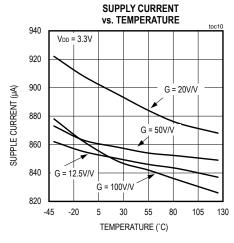
 $(V_{RS+} = V_{RS-} = 76V, V_{DD} = 3.3V, V_{SENSE} = V_{RS+} - V_{RS-} = 1mV, T_A = +25^{\circ}C$, unless otherwise noted.) (Note 2)

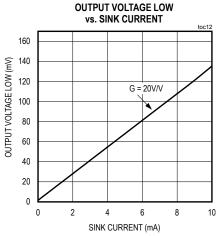










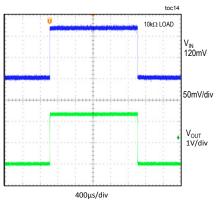


Typical Operating Characteristics (continued)

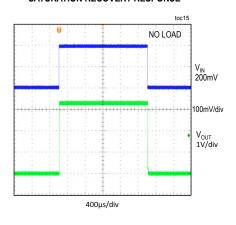
 $(V_{RS+} = V_{RS-} = 76V, V_{DD} = 3.3V, V_{SENSE} = V_{RS+} - V_{RS-} = 1mV, T_A = +25^{\circ}C, unless otherwise noted.)$ (Note 2)

SMALL-SIGNAL STEP RESPONSE toc13 V_{IN} 20mV 10mV/div V_{OUT} 200mV/div

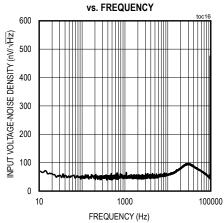
LARGE-SIGNAL STEP RESPONSE



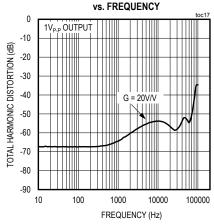
SATURATION RECOVERY RESPONSE



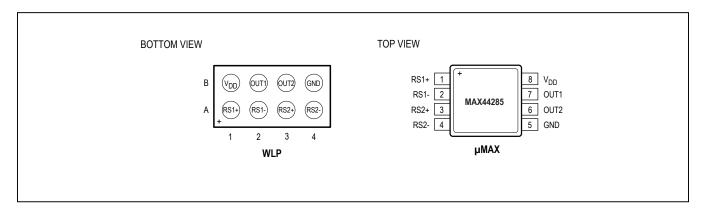
INPUT VOLTAGE-NOISE DENSITY







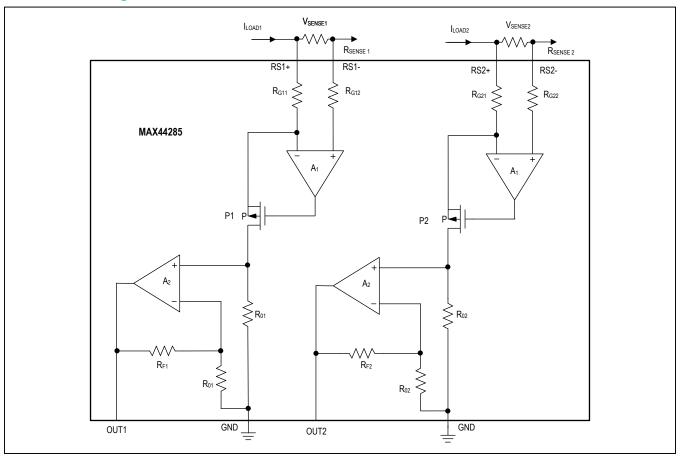
Pin Configuration



Pin Description

F	PIN	NAME	FUNCTION	
WLP	μМΑХ	NAME	FUNCTION	
A1	1	RS1+	Channel 1 External Resistor Power-Side Connection	
A2	2	RS1-	Channel 1 External Resistor Load-Side Connection	
A3	3	RS2+	Channel 2 External Resistor Power-Side Connection	
A4	4	RS2-	Channel 2 External Resistor Load-Side Connection	
B1	8	V _{DD}	Supply Voltage	
B2	7	OUT1	Output Channel 1	
В3	6	OUT2	Output Channel 2	
B4	5	GND	Ground	

Functional Diagram



Detailed Description

The MAX44285 high-side, current-sense amplifier features a 2.7V to 76V input common-mode range that is independent of supply voltage. This feature allows the monitoring of current out of a battery as low as 2.7V and enables high-side current sensing at voltages greater than the supply voltage (V_{DD}). The MAX44285 monitors current through a current-sense resistor and amplifies the voltage across the resistor.

High-side current monitoring does not interfere with the ground path of the load being measured, making the MAX44285 particularly useful in a wide range of high-voltage systems.

The MAX44285 operates as follows: current from the source flows through R_{SENSE} to the load (see <u>Functional Diagram</u>), creating a sense voltage, V_{SENSE} . The internal op amp A1 is used to force the current through an internal gain resistor R_{G11} at RS1+ pin, such that its voltage drop

equals the voltage drop (V_{SENSE}) across the external sense resistor (R_{SENSE}). The internal resistor at RS1- pin (R_{G12}) has the same value as R_{G11} to minimize error. The current through R_{G11} is sourced by a high-voltage p-channel FET. Its source current is the same as the drain current which flows through a second gain resistor, R₀₁, producing a voltage V_{R01} = V_{SENSE} x R₀₁/R_{G11}.

The output voltage V_{OUT1} is produced from a second op amp A2 with the gain (1 + R_{F1}/R₀₁). Hence, the V_{OUT1} = I_{LOAD1} x R_{SENSE1} (R₀₁/R_{G11}) x (1 + R_{F1}/ R₀₁) for channel 1 and V_{OUT2} = I_{LOAD2} x R_{SENSE2} (R₀₂/R_{G21}) x (1 + R_{F2}/ R₀₂) for channel 2. Internal resistor R₀₁ = R₀₂, R_{G11} = R_{G12} = R_{G21} = R_{G22}, R_{F1} = R_{F2}. The gain-setting resistors R₀₁, R₀₂, R_{G11}, R_{G12}, R_{G21}, R_{G22}, R_{F1}, and R_{F2} are available in Table 1):

Total gain = 12.5V/V for MAX44285L, 20V/V for the MAX44285T, 50V/V for the MAX44285F, and 100V/V for the MAX44285H.

Table 1. Gain-Setting Resistors

	GAIN (V/V)	R ₀₁ , R ₀₂ (k□)	R _{G11} , R _{G12} , R _{G21} , R _{G22} (k□)	$R_{\mathrm{F}1}$, $R_{\mathrm{F}2}$ (k \square)
MAX44285L	12.5	25	10	100
MAX44285T	20	25	10	175
MAX44285F	50	25	10	475
MAX44285H	100	25	10	975

Applications Information

Recommended Component Values

Ideally, the maximum load current develops the full-scale sense voltage across the current-sense resistor. Choose the gain needed to yield the maximum output voltage required for the application:

where V_{SENSE} is the full-scale sense voltage, 200mV for gain of 12.5V/V, 125mV for gain of 20V/V, 50mV for gain of 50V/V, 25mV for gain of 100V/V, and A_V is the gain of the device

In applications monitoring a high current, ensure that R_{SENSE} is able to dissipate its own I²R loss. If the resistor's power dissipation exceeds the nominal value, its value may drift or it may fail altogether. The MAX44285 senses a wide variety of currents with different senseresistor values.

Choosing the Sense Resistor

Choose R_{SENSE} based on the following criteria:

Voltage Loss: A high R_{SENSE} value causes the power-source voltage to degrade through IR loss. For minimal voltage loss, use the lowest R_{SENSE} value.

Accuracy: A high R_{SENSE} value allows lower currents measured more accurately. This is due to offsets becoming less significant when the sense voltage is larger. For best performance, select R_{SENSE} to provide approximately 200mV (gain of 12.5V/V), 125mV (gain of 20V/V), or 50mV (gain of 50V/V), 25mV (gain of 100V/V) of sense voltage for the full-scale current in each application.

Efficiency and Power Dissipation: At high current levels, the I²R losses in R_{SENSE} can be significant. Consider this when choosing the resistor value and its power dissipation (wattage) rating. In addition, the sense resistor's value might drift if it heats up excessively.

Inductance: Keep inductance low if I_{SENSE} has a large high-frequency component. Wire-wound resistors have the highest inductance, while metal film is somewhat better. Low-inductance, metal-film resistors are also available. Instead of being spiral wrapped around a core, as in metal-film or wire wound resistors, they are a straight band of metal and are available in values under 1Ω .

Take care to eliminate parasitic trace resistance from causing errors in the sense voltage because of the high currents that flow through R_{SENSE}. Either use a four terminal current-sense resistor or use Kelvin (force and sense) PCB layout techniques.

Base Station Application Circuit

An example of a typical application (Figure 1) of this high-voltage, high-precision current-sense amplifier is in base-station systems where there is a need to monitor the current flowing in the power amplifier. Such amplifiers, depending on the technology, can be biased up to 50V or 60V thus requiring a current-sense amplifier like the MAX44285 with high-voltage common mode. The very low input offset voltage of the MAX44285 minimizes the value of the external sense resistor thus resulting in system power-saving.

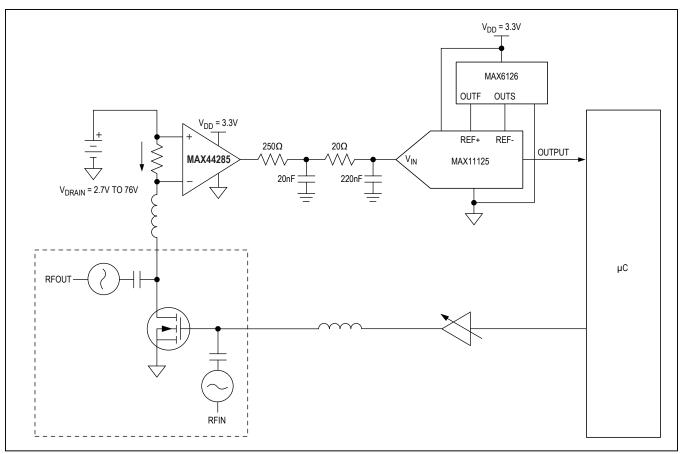


Figure 1. MAX44285 Used in Base-Station Application

Ordering Information

PART	GAIN (V/V)	TEMP RANGE	PIN-PACKAGE	TOP MARK
MAX44285LAWA+	12.5	-40°C to +125°C	8 WLP	+AAF
MAX44285LAUA+	12.5	-40°C to +125°C	8 µMAX	_
MAX44285TAWA+	20	-40°C to +125°C	8 WLP	+AAG
MAX44285TAUA+	20	-40°C to +125°C	8 µMAX	_
MAX44285FAWA+	50	-40°C to +125°C	8 WLP	+AAH
MAX44285FAUA+	50	-40°C to +125°C	8 µMAX	_
MAX44285HAWA+	100	-40°C to +125°C	8 WLP	+AAI
MAX44285HAUA+	100	-40°C to +125°C	8 μMAX	_

⁺Denotes a lead(Pb)-free/RoHS-compliant package.

Chip Information

PROCESS: BiCMOS

Package Information

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
8 WLP	W81A2+2	21-0210	Refer to Application Note 1891
8 µMAX	U8+1	21-0036	90-0092

MAX44285

Dual-Channel, High-Precision, High-Voltage, Current-Sense Amplifier

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	1/14	Initial release	_
1	2/14	Revised Pin Description, Functional Diagram, Detailed Description and added Table 1	7, 8, 9
2	7/14	Revised data sheet to change common-mode range from 36V to 76V	1–6. 8–10
3	12/14	Released WLP packages and updated Electrical Characteristics	2, 11
4	4/16	Updated unit in TOC1	4

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INA211CIRSWT LT6108AHMS8-1#PBF INA214CIRSWR LT1620CMS8#PBF INA215CIDCKR LTC6101HVBCS5#TRMPBF
LT6106HS5#PBF NTE1609 NTE926 NTE955MC NTE955S NTE955SM NTE978 NTE978C NTE978SM AD8211YRJZ-R2

AD8214ARMZ AD8214ARMZ-R7 AD8218BCPZ-WP AD8290ACPZ-R2 AD8290ACPZ-R7 AD22057RZ AD8215YRZ AD8210YRZ

AD22057RZ-RL AD8210YRZ-REEL7 AD8215WYRZ ADM4073FWRJZ-REEL7 LT1999HMS8-50F#WPBF LT1999HMS8-10F#WPBF
LTC6102HVIMS8#PBF LTC6101AIMS8#PBF LTC6102CMS8-1#PBF MAX4080TASA+T LT1787HS8#PBF LT1620CS8#PBF
LTC6115HMS#PBF